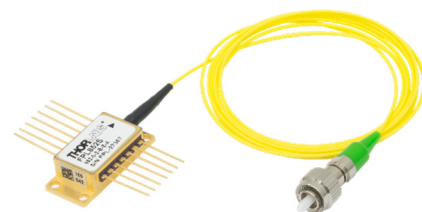


852 nm Fabry-Perot Laser Diode, 350 mW, Single Mode Fiber

FPL852S



Description

The FPL852S is an 852 nm Fabry-Perot laser diode based on quantum well epitaxial layer growth and a highly reliable ridge waveguide structure. This diode features high optical output power and slope efficiency. The laser diode is housed in a butterfly package with an integrated monitor photodiode, TEC, and a thermistor that allows the laser to be temperature controlled. The output is coupled to 1.0 m of FC/APC-terminated 780HP single mode fiber.

Specifications

| Absolute Maximum Ratings | |
|----------------------------|----------------|
| LD Reverse Voltage | 2.0 V |
| PD Reverse Voltage | 20 V |
| Current ^a | 950 mA |
| Power | 360 mW |
| Operating Case Temperature | 0 to 60 °C |
| Storage Temperature | -10 to 70 °C |
| Pin Code | 14 pin, Type 1 |



- a. Due to variations between each lot of laser diodes, some devices will produce an output power higher than the 360 mW max when driven with a 950 mA current. Do not drive the laser diode with a current that will cause the output power to exceed the specified maximum power rating. Operating in this regime can cause damage to the device.

| Specifications ^b | | | | |
|---|-----------------------|--------|---------------|--------|
| | Symbol | Min | Typical | Max |
| Center Wavelength | λ_c | 842 nm | 852 nm | 862 nm |
| Spectral Bandwidth (RMS) | $\Delta\lambda$ | - | 0.5 nm | 3.0 nm |
| Output Power CW @ I_{CW} | P_{CW} | 330 mW | 350 mW | 360 mW |
| Operating Current CW ^b | I_{CW} | - | 900 mA | 950 mA |
| Threshold Current | I_{TH} | - | 200 mA | 250 mA |
| Forward Voltage | V_F | - | 2.5 V | 3.0 V |
| Slope Efficiency | $\Delta P / \Delta I$ | | 0.5 W/A | - |
| Monitor Photodiode Current | I_{photo} | - | 0.8 mA | - |
| TEC Operation (Typical/Max @ $T_{CASE} = 25\text{ °C}/60\text{ °C}$) | | | | |
| TEC Current | I_{TEC} | - | 0.7 A | 2.5 A |
| TEC Voltage | V_{TEC} | - | 0.8 V | 3.2 V |
| Thermistor Resistance | R_{TH} | - | 10 k Ω | - |

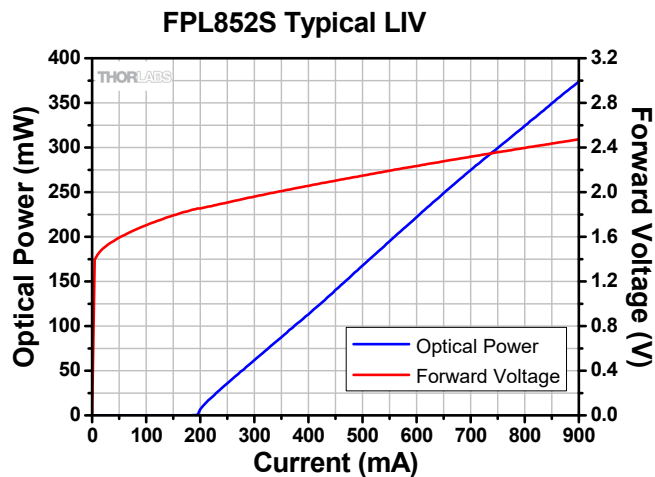
b. CW; $T_{CHIP} = 25\text{ °C}$, $T_{CASE} = 0 - 60\text{ °C}$

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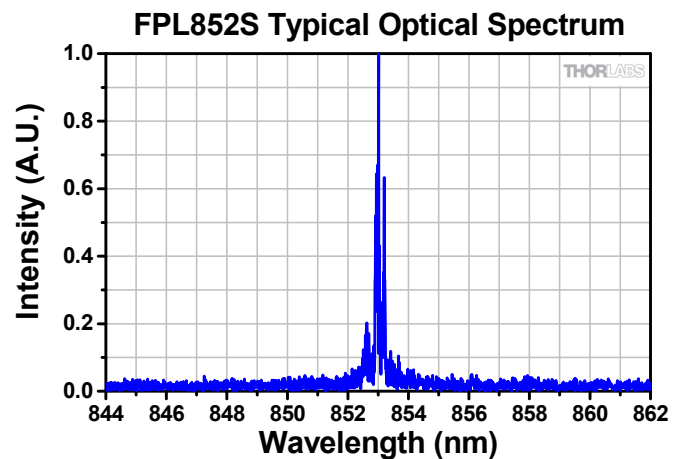
QTN019169-S01, Rev B

| Fiber Specifications | |
|----------------------|---------------------------|
| Fiber Type | 780HP |
| Numerical Aperture | 0.13 |
| Core Diameter | 4.4 μm |
| Fiber Length | 1.0 m |
| Connector | FC/APC, 2.0 mm Narrow Key |

Typical Performance Plots

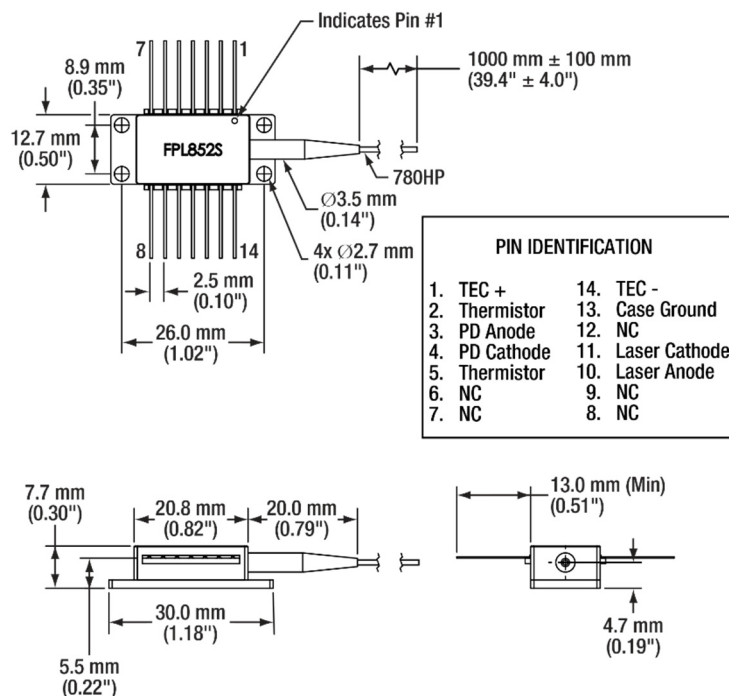


The device was held at 25 °C.



While the laser diode was held at 25 °C, it was driven at the current required to reach an output power of 350 mW.

Drawings



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